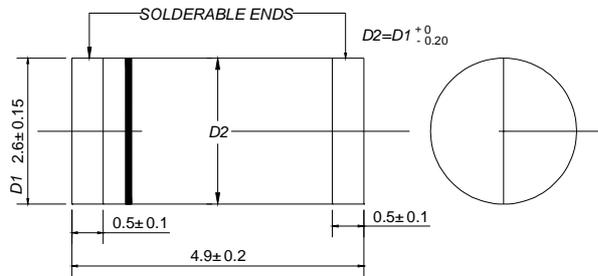




DL4933 THRU DL4937

SURFACE MOUNT RECTIFIERS
VOLTAGE RANGE: 50 --- 600 V CURRENT: 1.0 A

DO-213AB



Dimensions in millimeters

FEATURES

Glass passivated device
 Ideal for surface mounted applications
 Low leakage
 Low forward voltage drop
 High current capability
 Easily cleaned with Alcohol, Isopropnol and similar solvents
 The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

Case: JEDEC DO-213AB, molded plastic
 Terminals: Solderable per MIL- STD-202, Method 208
 Polarity: Color band denotes cathode
 Weight: 0.0046 ounces, 0.116 grams
 Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

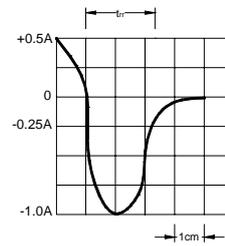
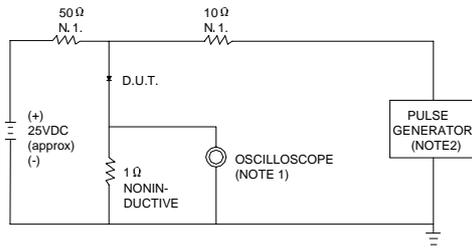
MDD Catalog Number		DL4933	DL4934	DL4935	DL4936	DL4937	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	V
Maximum average forward rectified current @ $T_A=55$	$I_{(AV)}$	1.0					A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	30					A
Maximum instantaneous forward voltage @ 1.0A	V_F	1.2					V
Maximum reverse current @ $T_A=25$ at rated DC blocking voltage @ $T_A=125$	I_R	5.0 100					μA
Maximum reverse recovery time (Note1)	t_{rr}	200					ns
Typical junction capacitance (Note2)	C_j	15					pF
Maximum thermal resistance (Note3)	$R_{\theta JL}$	30					/W
Maximum thermal resistance (Note4)	$R_{\theta JA}$	75					/W
Operating junction temperature range	T_j	-55 --- + 150					
Storage temperature range	T_{STG}	-55 --- + 150					

NOTE: 1. Test conditions: $I_F=1.0A, V_R=30V$.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Thermal resistance junction to terminal 6.0mm² copper pads to each terminal.
 4. Thermal resistance junction to ambient 6.0mm² copper pads to each terminal.

MDD ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES DL4933 THRU DL4937

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ. 22pF.
 2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50 Ω.

SET TIME BASE FOR 80ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

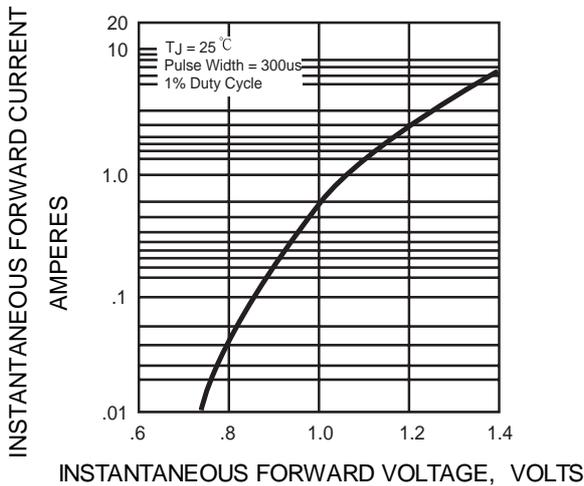


FIG.3 -- FORWARD DERATING CURVE

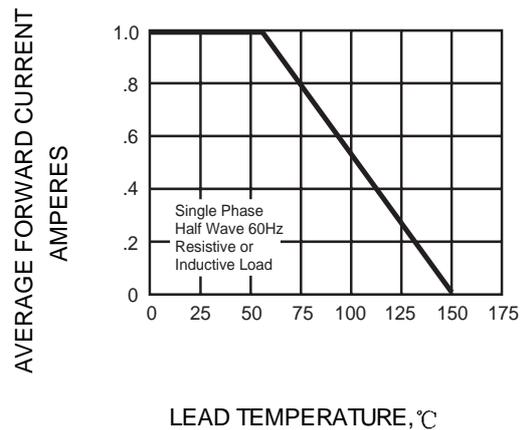


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

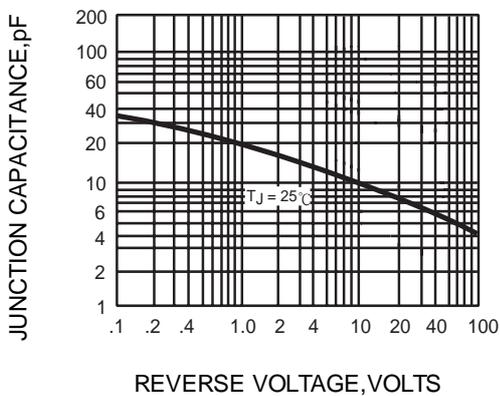


FIG.5 -- PEAK FORWARD SURGE CURRENT

